



**TET ESTEL AS**  
ESTONIA

**March**  
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**Series**  
**T153-2000**

**Phase Control Press-Pack**  
**Thyristor**  
**Type T153-2000**

Center amplifying gate  
Low on-state and switching losses  
Designed for traction and industrial applications

Maximum mean on-state current	$I_{TAV}$	<b>2000 A</b>			
Maximum repetitive peak off-state and reverse voltage	$U_{DRM}$	<b>200 ÷ 600 V</b>			
Turn-off time	$U_{RRM}$	<b>100; 125; 160 <math>\mu</math>s</b>			
	$t_q$				
$U_{DRM}, U_{RRM}, V$	200	300	400	500	600
Voltage code	2	3	4	5	6
$T_{vj}, ^\circ C$	- 60 ÷ 125				

**MAXIMUM ALLOWABLE RATINGS**

Symbols and parameters		Units	T153-2000	Conditions
$I_{TAV}$	Mean on-state current	A	2000 2880	$T_c=80^\circ C$ , $T_c=55^\circ C$ , 180° half-sine wave, 50 Hz
$I_{TRMS}$	RMS on-state current	A	3140	$T_c=80^\circ C$
$I_{TSM}$	Surge on-state current	kA	38 40	$T_{vj}=125^\circ C$ $T_{vj}=25^\circ C$ tp=10 ms $U_R=0$
$I^2t$	Limiting load integral	$kA^2s$	7220 8000	$T_{vj}=125^\circ C$ $T_{vj}=25^\circ C$
$U_{DRM}, U_{RRM}$	Repetitive peak off-state and reverse voltage	V	200÷600	$T_j \min \leq T_{vj} \leq T_{jM}$ 180° half-sine wave, 50 Hz Gate open
$U_{DSM}, U_{RSM}$	Non-repetitive peak off-state and reverse voltage	V	300÷700	$T_j \min \leq T_{vj} \leq T_{jM}$ 180° half-sine wave tp=10 ms, Single pulse Gate open
(diT/dt) crit	Critical rate of rise of on-state current : non - repetitive repetitive	A/ $\mu$ s	400 200	$T_{vj}=125^\circ C; U_D=0,67 U_{DRM}$ , Gate pulse : 10V,5 $\Omega$ , 1 $\mu$ s rise time, 10 $\mu$ s
$U_{RGM}$	Peak reverse gate voltage	V	5	$T_j \min \leq T_{vj} \leq T_{jM}$
$T_{stg}$	Storage temperature	$^\circ C$	-60÷80	
$T_{vj}$	Junction temperature	$^\circ C$	-60÷125	

**CHARACTERISTICS**

$U_{TM}$	Peak on-state voltage	V	1,5	$T_{vj}=25^\circ C, I_{TM}=3,14 I_{TAV}$
$U_{T(To)}$	Threshold voltage	V	0,85	$T_{vj}=125^\circ C$
$R_T$	On-state slope resistance	m $\Omega$	0,07	1,57 $I_{TAV} < I_T < 4,71 I_{TAV}$
$I_{DRM}$ $I_{RRM}$	Repetitive peak off-state and reverse current	mA	100 100	$T_{vj}=125^\circ C$ , $U_D = U_{DRM}$ $U_R = U_{RRM}$

